

SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

N-Channel Silicon MOSFET SCH1433 — General-Purpose Switching Device **Applications**

Features

- 1.8V drive.
- · Halogen free compliance.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	ID		3.5	A
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	14	A
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² ×0.8mm)	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μΑ
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =1.5A	1.68	2.8		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=1.5A, VGS=4.5V		49	64	mΩ
	RDS(on)2	ID=1A, VGS=2.5V		68	95	mΩ
	R _{DS} (on)3	ID=0.5A, VGS=1.8V		99	149	mΩ

Marking : ZJ

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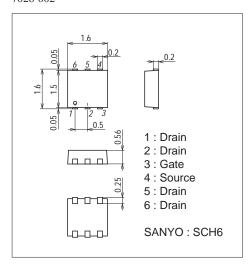
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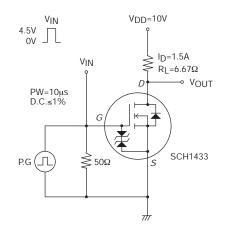
Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		260		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		65		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		50		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		6.2		ns
Rise Time	tr	See specified Test Circuit.		19		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		30		ns
Fall Time	tf	See specified Test Circuit.		28		ns
Total Gate Charge	Qg	VDS=10V, VGS=4.5V, ID=3.5A		2.8		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4.5V, I _D =3.5A		0.6		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =4.5V, I _D =3.5A		0.9		nC
Diode Forward Voltage	VSD	IS=3.5A, VGS=0V		0.85	1.2	V

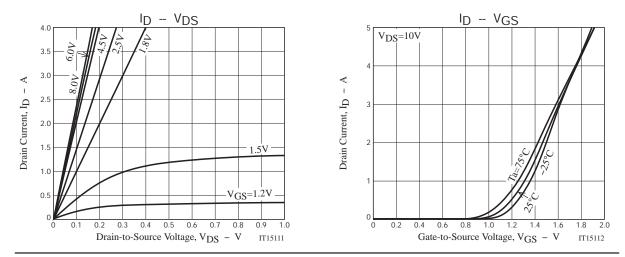
Package Dimensions

unit : mm (typ) 7028-002

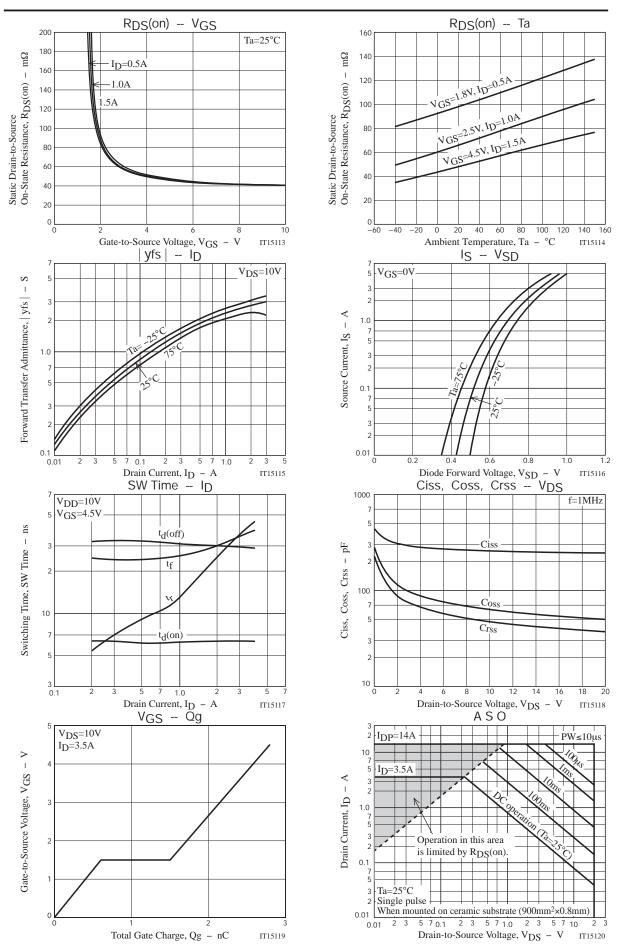


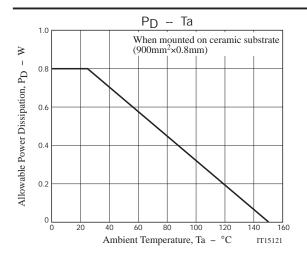
Switching Time Test Circuit





SCH1433





Note on usage : Since the SCH1433 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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